













OPA827

JAJS197I - NOVEMBER 2006 - REVISED JULY 2016

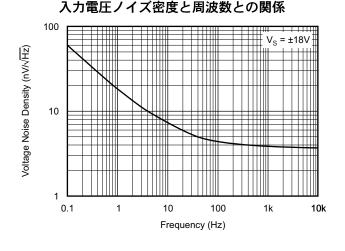
OPA827 低ノイズ、高精度、JFET入力 オペアンプ

1 特長

- 入力電圧ノイズ密度: 1kHzにおいて 4nV/√Hz
- 入力電圧ノイズ: 0.1Hz~10Hz: 250nV_{PP}
- 入力バイアス電流: 10pA (最大値)
- 入力オフセット電圧: 150µV (最大値)
- 入力オフセット・ドリフト: 2µV/℃ (最大値)
- ゲイン帯域幅: 22MHzスルーレート: 28V/μs静止電流: 4.8mA/Ch
- 広い電源電圧範囲: ±4V~±18V
- パッケージ: 8ピンSOICおよび8ピンVSSOP

2 アプリケーション

- ADCドライバ
- DAC出力バッファ
- 試験用機器
- 医療用機器
- PLLフィルタ
- 地震関連の応用
- トランスインピーダンス・アンプ
- 積分器
- アクティブ・フィルタ



3 概要

OPA827シリーズのJFETオペアンプは、優れたDC精度とAC性能を持ち合わせています。これらのアンプは、オフセット電圧が低く(最大値150 μ V)、温度によるドリフト係数が非常に低く(標準値0.5 μ V/°C)、バイアス電流が低く(標準値3pA)、0.1Hz~10Hzのノイズが非常に低い(標準値250nV $_{PP}$)製品です。このデバイスは \pm 4V~ \pm 18Vの広い電源電圧範囲、低い消費電流(標準値4.8 \pm 8 \pm 8 \pm 8 \pm 90で動作します。

ゲイン帯域幅積(GBW)が22MHz、スルー・レートが28V/µsという優れたAC特性や、高精度のDC特性から、OPA827シリーズは16~18ビットのミクスト・シグナル・システム、トランスインピーダンス(I/V変換)アンプ、フィルタ、高精度の±10Vフロントエンド、プロ用オーディオなど広範なアプリケーションに適しています。

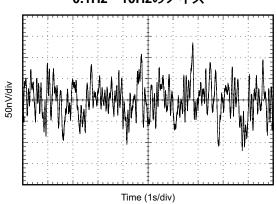
OPA827は、8ピンSOICおよび8ピンVSSOPの表面実装 パッケージで供給され、-40℃~125℃で仕様が規定され ています。

製品情報⁽¹⁾

型番	パッケージ	本体サイズ(公称)
OPA827	SOIC (8)	4.90mm×3.91mm
UPA621	VSSOP (8)	3.00mm×3.00mm

(1) 提供されているすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。

0.1Hz~10Hzのノイズ



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4 改訂履歴

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Revision H (May 2012) から Revision I に変更 • 「ESD定格」表、「機能説明」セクション、「デバイスの機能モード」セクション、「アプリケーションと実装」セクション、「電源に関

Revision G (February 2012) から Revision H に変更

Revision F (March 2009) から Revision G に変更

•	特長の箇条書きの「入力バイアス電流」と「入力オフセット・ドリフト」を変更	1
•	製品のステータスを混在ステータスから量産データへ変更	1
•	「概要」セクションの最初の段落にあるアンプのドラフトとバイアス電流の記述を変更	. 1

- 「概要」セクションの最初の段格にあるアンノのトラフトとハイアス電流の記述を変更 1
 Deleted high grade (OPA827I) option and footnote 2 from *Package/Ordering Information* table 4
 Deleted high grade (OPA827I) option from Electrical Characteristics table 6
- Changed Offset Voltage, Input Offset Voltage Drift parameter typical and maximum specifications in Electrical Characteristics table
 Changed Input Bias Current section specifications in Electrical Characteristics table

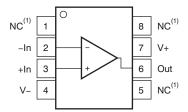




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wv	vw.ti.com	JAJS197I - NOVEMBER 2006-REVISED JULY 2016
•	Updated Figure 11	8
•	Updated Figure 12	
	Updated Figure 14	

5 Pin Configuration and Functions

D and DGK Packages 8-Pin SOIC and VSSOP Top View



(1) NC denotes no internal connection.

Pin Functions

PIN		1/0	DESCRIPTION	
NO.	NAME	I/O	DESCRIPTION	
+IN	3	1	Noninverting input	
-IN	2	1	Inverting input	
NC	1, 5, 8	_	No internal connection (can be left floating)	
OUT	6	0	Output	
V+	7	_	Positive power supply	
V-	4	_	Negative power supply	



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

	MIN	MAX	UNIT
Supply voltage, $V_S = (V+) - (V-)$		40	V
Input voltage (2)	(V-) - 0.5	(V+) + 0.5	V
Input current ⁽²⁾		±10	mA
Differential input voltage		±V _S	V
Output short-circuit ⁽³⁾	Contin	uous	
Operating temperature, T _A	– 55	150	°C
Junction temperature, T _J		150	°C
Storage temperature, T _{stg}	– 65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
V	Floatroototic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±4000	\/
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
V_S	Supply voltage	±4	±18	V
T _A	Specified temperature	-40	125	င့

6.4 Thermal Information

			OPA827		
	THERMAL METRIC ⁽¹⁾	D (SOIC)	DGK (VSSOP)	UNIT	
		8 PINS	8 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	160	180	°C/W	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	75	55	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	60	130	°C/W	
ΨЈТ	Junction-to-top characterization parameter	9	_	°C/W	
ΨЈВ	Junction-to-board characterization parameter	50	120	°C/W	
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	_	_	°C/W	

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

⁽²⁾ Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5 V beyond the supply rails must be current-limited to 10 mA or less.

⁽³⁾ Short-circuit to V_S/2 (ground in symmetrical dual-supply setups).

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.5 Electrical Characteristics

at $V_S = \pm 4$ V to ± 18 V, $T_A = 25$ °C, $R_L = 10$ k Ω connected to midsupply, and $V_{CM} = V_{OUT} =$ midsupply (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFFSET VOL	TAGE					
V _{os}	Input offset voltage	$V_S = \pm 15 \text{ V}, V_{CM} = 0 \text{ V}$		75	150	μV
dV _{OS} /dT	Input offset voltage drift	$T_A = -40$ °C to 125°C		0.1	2	μV/°C
DODD	Input offset voltage vs power			0.2	1	1/0/
PSRR	supply	$T_A = -40$ °C to 125°C			3	μV/V
INPUT BIAS C	CURRENT					
				±3	±10	pA
I _B	Input bias current	$T_A = -40$ °C to 85°C			±500	pA
		$T_A = -40$ °C to 125°C			±5	nA
Ios	Input Offset Current			±3	±10	pA
NOISE						
	Input Voltage Noise:	$f = 0.1 \text{ Hz to } 10 \text{ Hz}, V_S = \pm 18 \text{ V}, V_{CM} = 0 \text{ V}$		250		nV_{PP}
e _n	1 N /	$f = 1 \text{ kHz}, V_S = \pm 18 \text{ V}, V_{CM} = 0 \text{ V}$		4		\ //
	Input Voltage Noise Density	f = 10 kHz, V _S = ±18 V, V _{CM} = 0 V		3.8		nV/√ Hz
i _n	Input current noise density	f = 1 kHz, V _S = ±18 V, V _{CM} = 0 V		2.2		fA/√ Hz
INPUT VOLTA	GE RANGE					
V _{CM}	Common-mode voltage range		(V-) + 3		(V+) - 3	V
	Common-mode rejection ratio	$(V-) + 3 V \le V_{CM} \le (V+) - 3 V, V_S < 10 V$	104	114		
		$(V-) + 3 V \le V_{CM} \le (V+) - 3 V, V_S \ge 10 V$	114	126		
CMRR		$(V-) + 3 V \le V_{CM} \le (V+) - 3 V, V_S < 10 V$ $T_A = -40^{\circ}C$ to 125°C	100			dB
		$(V-) + 3 V \le V_{CM} \le (V+) - 3 V, V_S \ge 10 V$ $T_A = -40^{\circ}C \text{ to } 125^{\circ}C$	110			
INPUT IMPED	ANCE					
Differential				10 ¹³ 9		Ω ∥ pF
Common-mod	e			10 ¹³ 9		Ω pF
OPEN-LOOP	GAIN		"			
		$(V-) + 3 V \le V_O \le (V+) - 3 V, R_L = 1 k\Omega$	120	126		
A _{OL}	Open-loop voltage gain	$(V-) + 3 V \le V_O \le (V+) - 3 V$, $R_L = 1 k\Omega$ $T_A = -40^{\circ}C$ to 125°C	114			dB
FREQUENCY	RESPONSE					
GBW	Gain-bandwidth product	G = +1		22		MHz
SR	Slew rate	G = -1	20	28		V/µs
		±0.01%, 10-V step, G = -1, C _L = 100 pF		550		ns
t_S	Settling time	0.00075% (16-bit), 10-V step, $G = -1$, $C_L = 100 \text{ pF}$		850		ns
	Overload recovery time	Gain = -10		150		ns
THD.N	Total Harmonic Distortion +	G = +1, f = 1 kHz		0.00004%		
THD+N	Noise	$V_O = 3 V_{RMS}, R_L = 600 \Omega$		-128		dB



Electrical Characteristics (continued)

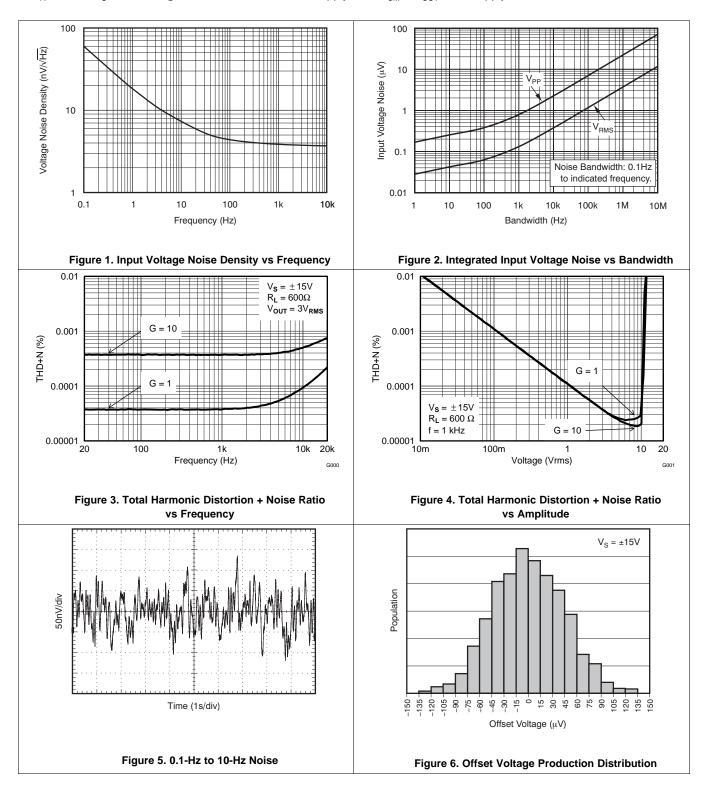
at $V_S = \pm 4$ V to ± 18 V, $T_A = 25$ °C, $R_L = 10$ k Ω connected to midsupply, and $V_{CM} = V_{OUT} =$ midsupply (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT	
OUTPUT						
		$R_L = 1 \text{ k}\Omega, A_{OL} > 120 \text{ dB}$	(V-) + 3	(V+) - 3		
	Voltage output swing	$R_L = 1 \text{ k}\Omega, A_{OL} > 114 \text{ dB}$ $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$	(V–) + 3	(V+) – 3	V	
I _{OUT}	Output current	V _S - V _{OUT} < 3 V		30	mA	
I _{SC}	Short-circuit current		±55	±65	mA	
C _{LOAD}	Capacitive load drive		See Typica	See Typical Characteristics		
Z _O	Open-loop output impedance		See Typica	See Typical Characteristics		
POWER SU	PPLY					
Vs	Specified voltage		±4	±18	V	
	Quiescent current	I _{OUT} = 0A		4.8 5.2	A	
IQ	(per amplifier)	$T_A = -40$ °C to 125°C		6	mA	

TEXAS INSTRUMENTS

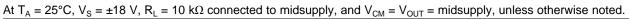
6.6 Typical Characteristics

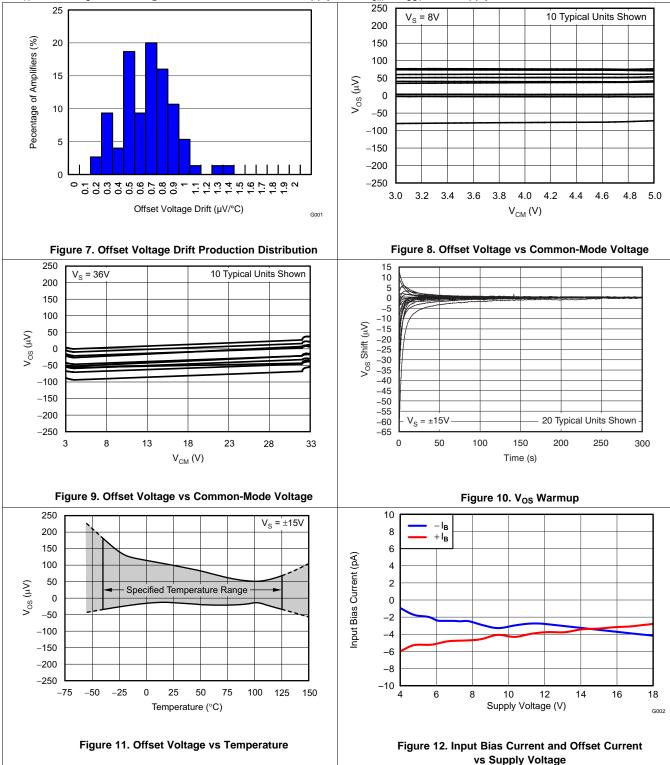
At $T_A = 25$ °C, $V_S = \pm 18$ V, $R_L = 10$ k Ω connected to midsupply, and $V_{CM} = V_{OUT} =$ midsupply, unless otherwise noted.





Typical Characteristics (continued)

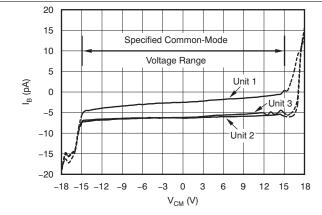




TEXAS INSTRUMENTS

Typical Characteristics (continued)

At $T_A = 25$ °C, $V_S = \pm 18$ V, $R_L = 10$ k Ω connected to midsupply, and $V_{CM} = V_{OUT} =$ midsupply, unless otherwise noted.



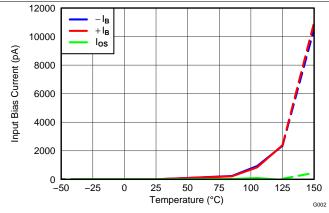
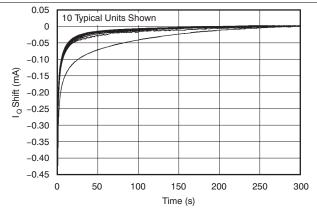


Figure 13. Input Bias Current vs Common-Mode Voltage

Figure 14. Input Bias Current vs Temperature



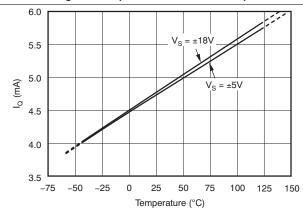
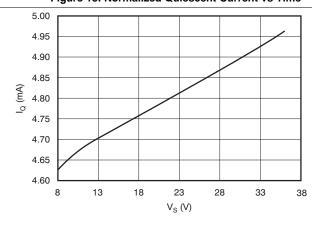


Figure 15. Normalized Quiescent Current vs Time

Figure 16. Quiescent Current vs Temperature



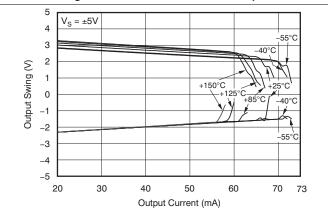
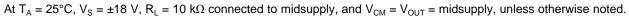


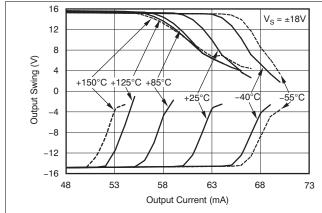
Figure 17. Quiescent Current vs Supply Voltage

Figure 18. Output Voltage Swing vs Output Current



Typical Characteristics (continued)





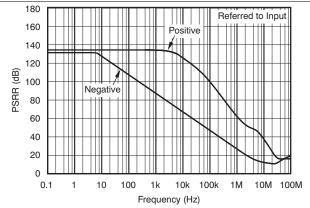
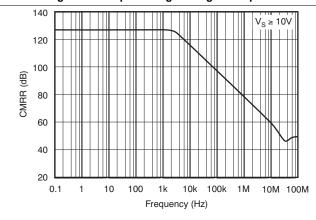


Figure 19. Output Voltage Swing vs Output Current





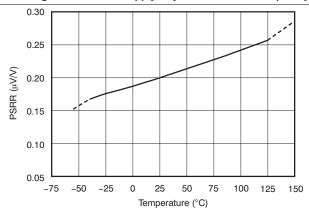
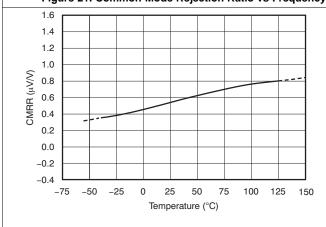


Figure 21. Common-Mode Rejection Ratio vs Frequency

Figure 22. Power-Supply Rejection Ratio vs Temperature



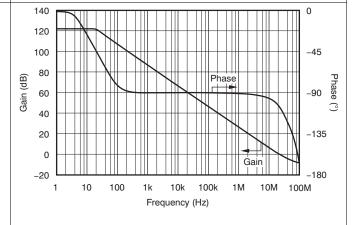


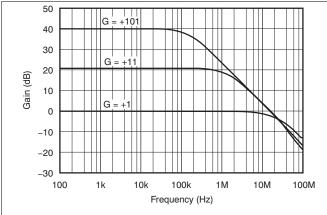
Figure 23. Common-Mode Rejection Ratio vs Temperature

Figure 24. Open-Loop Gain and Phase vs Frequency

TEXAS INSTRUMENTS

Typical Characteristics (continued)

At $T_A = 25$ °C, $V_S = \pm 18$ V, $R_L = 10$ k Ω connected to midsupply, and $V_{CM} = V_{OUT} =$ midsupply, unless otherwise noted.



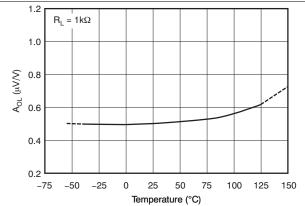
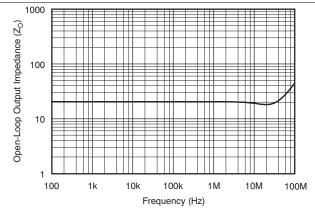


Figure 25. Closed-Loop Gain vs Frequency

Figure 26. Open-Loop Gain vs Temperature



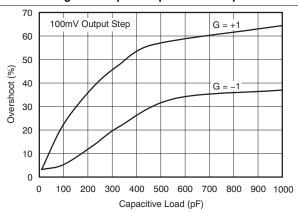
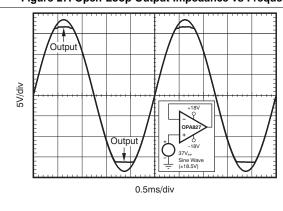


Figure 27. Open-Loop Output Impedance vs Frequency

Figure 28. Small-Signal Overshoot vs Capacitive Load



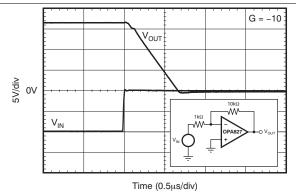
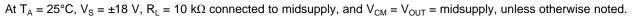


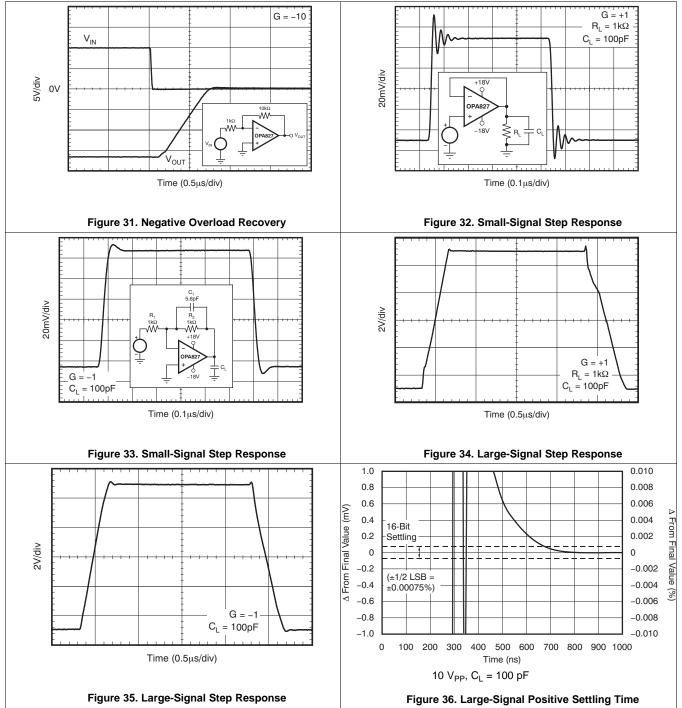
Figure 29. No Phase Reversal

Figure 30. Positive Overload Recovery



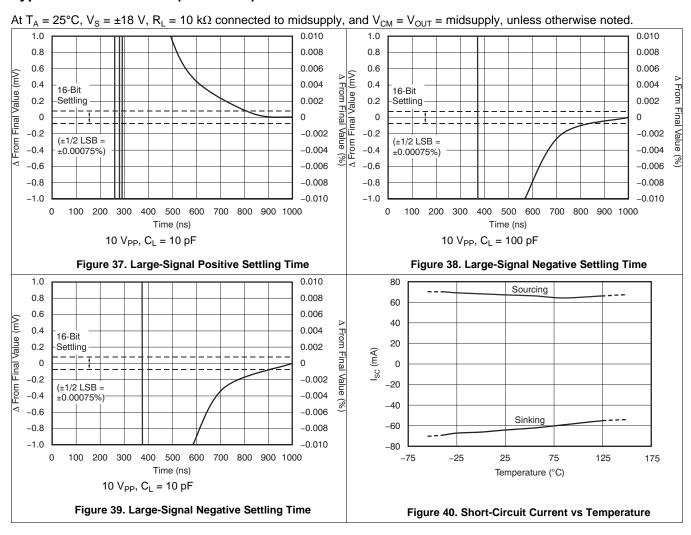
Typical Characteristics (continued)





TEXAS INSTRUMENTS

Typical Characteristics (continued)



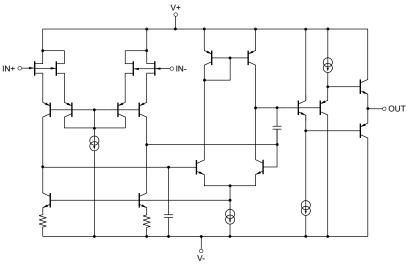


7 Detailed Description

7.1 Overview

The OPA827 is a unity-gain stable, precision operational amplifier with very low noise, input bias current, and input offset voltage. Applications with noisy or high-impedance power supplies require decoupling capacitors placed close to the device pins. In most cases, 0.1-µF capacitors are adequate.

7.2 Functional Block Diagram



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7.3 Feature Description

The OPA827 is a precision JFET amplifier with low input offset voltage, low input offset voltage drift and low noise. High impedance inputs make the OPA827 ideal for high source impedance applications and transimpedance applications.

7.3.1 Operating Voltage

The OPA827 series of op amps can be used with single or dual supplies from an operating range of $V_S = 8 \text{ V } (\pm 4 \text{ V})$ and up to $V_S = 36 \text{ V } (\pm 18 \text{ V})$. This device does not require symmetrical supplies; it only requires a minimum supply voltage of 8 V. Supply voltages higher than 40 V ($\pm 20 \text{ V}$) can permanently damage the device; see *Absolute Maximum Ratings*. Key parameters are specified over the operating temperature range, $T_A = -40^{\circ}\text{C}$ to 125°C. Key parameters that vary over the supply voltage or temperature range are shown in *Typical Characteristics* of this data sheet.

7.3.2 Noise Performance

Figure 41 shows the total circuit noise for varying source impedances with the operational amplifier in a unity-gain configuration (with no feedback resistor network and therefore no additional noise contributions). The OPA827 (GBW = 22 MHz) and OPA211 (GBW = 80 MHz) are both shown in this example with total circuit noise calculated. The op amp itself contributes both a voltage noise component and a current noise component. The voltage noise is commonly modeled as a time-varying component of the offset voltage. The current noise is modeled as the time-varying component of the input bias current and reacts with the source resistance to create a voltage component of noise. Therefore, the lowest noise op amp for a given application depends on the source impedance. For low source impedance, current noise is negligible, and voltage noise generally dominates. The OPA827 family has both low voltage noise and lower current noise because of the FET input of the op amp. Very low current noise allows for excellent noise performance with source impedances greater than 10 k Ω . OPA211 has lower voltage noise and higher current noise. The low voltage noise makes the OPA211 a better choice for low source impedances (less than 2 k Ω). For high source impedance, current noise may dominate, and makes the OPA827 series amplifier the better choice.



The equation in Figure 41 shows the calculation of the total circuit noise, with these parameters:

- e_n = voltage noise
- i_n = current noise
- R_S = source impedance
- $k = Boltzmann's constant = 1.38 \times 10^{-23} J/K$
- T = temperature in kelvins

For more details on calculating noise, see Basic Noise Calculations.

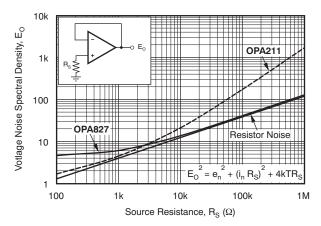


Figure 41. Noise Performance of the OPA827 and OPA211 in Unity-Gain Buffer Configuration

7.3.3 Basic Noise Calculations

Low-noise circuit design requires careful analysis of all noise sources. External noise sources can dominate in many cases; consider the effect of source resistance on the overall noise performance of the op amp. Total noise of the circuit is the root-sum-square combination of all noise components.

The resistive portion of the source impedance produces thermal noise proportional to the square root of the resistance. This function is plotted in Figure 41. The source impedance is usually fixed; consequently, select the op amp and the feedback resistors to minimize the respective contributions to the total noise.

Figure 42 illustrates both noninverting (A) and inverting (B) op amp circuit configurations with gain. In circuit configurations with gain, the feedback network resistors also contribute noise. The current noise of the op amp reacts with the feedback resistors to create additional noise components.

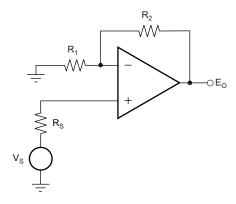
The feedback resistor values can generally be chosen to make these noise sources negligible.

NOTE

Low-impedance feedback resistors load the output of the amplifier. The equations for total noise are shown for both configurations shown in both configurations in Figure 42.



A) Noise in Noninverting Gain Configuration

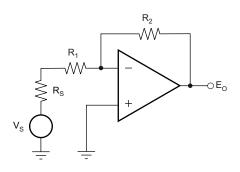


Noise at the output:

$$\begin{split} E_{O}^{\ 2} = & \left[1 + \frac{R_{2}}{R_{1}}\right]^{2} \, e_{n}^{\ 2} + e_{1}^{\ 2} + e_{2}^{\ 2} + \left(i_{n}R_{2}\right)^{2} + e_{S}^{\ 2} + \left(i_{n}R_{S}\right)^{2} \left[1 + \frac{R_{2}}{R_{1}}\right]^{2} \end{split}$$
 Where $e_{S} = \sqrt{4kTR_{S}} \cdot \left[1 + \frac{R_{2}}{R_{1}}\right] = \text{thermal noise of } R_{S}$
$$e_{1} = \sqrt{4kTR_{1}} \cdot \left[\frac{R_{2}}{R_{1}}\right] = \text{thermal noise of } R_{1}$$

$$e_{2} = \sqrt{4kTR_{2}} = \text{thermal noise of } R_{2}$$

B) Noise in Inverting Gain Configuration



Noise at the output:

$$\begin{split} &E_O^2 = \left(1 + \frac{R_2}{R_1 + R_S}\right)^2 \, e_n^{\ 2} + e_1^{\ 2} + e_2^{\ 2} + (i_n R_2)^2 + e_S^{\ 2} \end{split}$$
 Where $e_S = \sqrt{4kTR_S} \cdot \left(\frac{R_2}{R_1 + R_S}\right) = \text{thermal noise of } R_S$
$$e_1 = \sqrt{4kTR_1} \cdot \left(\frac{R_2}{R_1 + R_S}\right) = \text{thermal noise of } R_1$$

$$e_2 = \sqrt{4kTR_2} = \text{thermal noise of } R_2$$

For the OPA827 series op amps at 1kHz, $e_n = 4nV/\sqrt{Hz}$ and $i_n = 2.2fA/\sqrt{Hz}$.

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Figure 42. Noise Calculation in Gain Configurations

7.3.4 Total Harmonic Distortion Measurements

The OPA827 series op amps have excellent distortion characteristics. THD + Noise is below 0.0001% (G = +1, V_O = 3 V_{RMS}) throughout the audio frequency range, 20 Hz to 20 kHz, with a 600- Ω load (see Figure 3).

The distortion produced by the OPA827 series is below the measurement limit of many commercially available testers. However, a special test circuit (illustrated in Figure 43) can be used to extend the measurement capabilities.

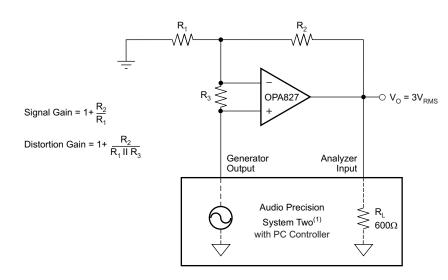
Op amp distortion can be considered an internal error source that can be referred to the input. Figure 43 shows a circuit that causes the op amp distortion to be 101 times greater than that distortion normally produced by the op amp. The addition of R_3 to the otherwise standard noninverting amplifier configuration alters the feedback factor or noise gain of the circuit. The closed-loop gain is unchanged, but the feedback available for error correction is reduced by a factor of 101, thus extending the resolution by 101.

NOTE

the input signal and load applied to the op amp are the same as with conventional feedback without R_3 . The value of R_3 must be kept small to minimize its effect on the distortion measurements.



The validity of this technique can be verified by duplicating measurements at high gain and high frequency where the distortion is within the measurement capability of the test equipment. Measurements for this data sheet were made with an Audio Precision System Two distortion and noise analyzer, which greatly simplifies such repetitive measurements. This measurement technique, however, can be performed with manual distortion measurement instruments.



SIGNAL GAIN	DISTORTION GAIN	R ₁	R_2	R ₃
1	101	œ	1kΩ	10Ω
11	101	100Ω	1kΩ	11Ω

NOTE: (1) Measurement BW = 80kHz.

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Figure 43. Distortion Test Circuit

7.3.5 Capacitive Load and Stability

The combination of gain bandwidth product (GBW) and near constant open-loop output impedance (Z_O) over frequency gives the OPA827 the ability to drive large capacitive loads. Figure 44 shows the OPA827 connected in a buffer configuration (G = +1) while driving a 2.2- μ F ceramic capacitor (with an ESR value of approximately 0 Ω). The small overshoot and fast settling time are results of good phase margin. This feature provides superior performance compared to the competition. Figure 44 and Figure 45 were taken without any resistive load in parallel to shorten the ringing time.

In Figure 45, the OPA827 is driving a 2.2-µF tantalum capacitor. A relatively small ESR that is internal to the capacitor additionally improves phase margin and provides an output waveform with no ringing and minimal overshoot. Figure 45 shows a stable system that can be used in almost any application.

Capacitive load drive depends on the gain and overshoot requirements of the application. Capacitive loads limit the bandwidth of the amplifier. Increasing the gain enhances the ability of the amplifier to drive greater capacitive loads (see Figure 28).

7.3.6 Phase-Reversal Protection

The OPA827 family has internal phase-reversal protection. Many FET-input op amps exhibit a phase reversal when the input is driven beyond its linear common-mode range. This condition is most often encountered in noninverting circuits when the input is driven beyond the specified common-mode voltage range, causing the output to reverse into the opposite rail. The input circuitry of the OPA827 prevents phase reversal with excessive common-mode voltage; instead, the output limits into the appropriate rail (see Figure 29).



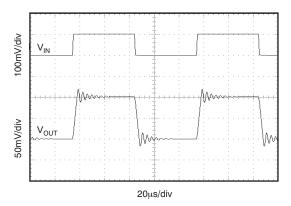


Figure 44. OPA827 Driving 2.2-µF Ceramic Capacitor

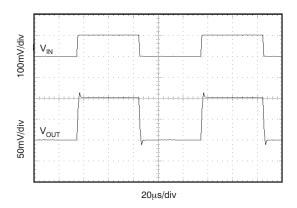


Figure 45. OPA827 Driving 2.2-µF Tantalum Capacitor

7.3.7 Transimpedance Amplifier

The gain bandwidth, low voltage noise, and current noise of the OPA827 series make them ideal wide bandwidth transimpedance amplifiers in a photo-conductive application. High transimpedance gains with feedback resistors greater than 100 k Ω benefit from the low input current noise (2.2 fA/Hz) of the JFET input. Low voltage noise is important because photodiode capacitance causes the effective noise gain in the circuit to increase at high frequencies. Total input capacitance of the circuit limits the overall gain bandwidth of the amplifier and is addressed below. Figure 46 shows a photodiode transimpedance application.

7.3.7.1 Key Transimpedance Points

- The total input capacitance (C_{TOT}) consists of the photodiode junction capacitance, and both the common-mode and differential input capacitance of the operational amplifier.
- The desired transimpedance gain, $V_{OUT} = I_D R_F$.
- The Unity Gain Bandwidth Product (UGBW) (22 MHz for the OPA827).

With these three variables set, the feedback capacitor value (C_F) can be calculated to ensure stability. C_{STRAY} is the parasitic capacitance of the PCB and passive components, which is approximately 0.5 pF.

To ensure 45° phase margin, the minimal amount of feedback capacitance can be calculated using Equation 1.

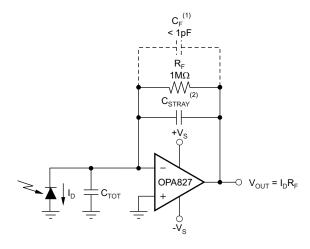
$$C_{F}\left(\frac{1}{4\pi R_{F}UGBW}\right)\left(1+\sqrt{1+\left(8\pi C_{TOT}R_{F}UGBW\right)}\right) \tag{1}$$



Bandwidth (f_{-3dB}) can be calculated using Equation 2.

$$f_{-3dB} = \sqrt{\frac{UGBW}{2\pi R_F(C_{TOT})}} Hz$$
 (2)

These equations result in maximum transimpedance bandwidth. For additional information, refer to *Compensate Transimpedance Amplifiers Intuitively*, available for download at www.ti.com.



NOTES: (1) C_F is optional to prevent gain peaking. (2) C_{STRAY} is the stray capacitance of R_F (typically, 2pF for a surface-mount resistor). Copyright © 2016, Texas Instruments Incorporated

Figure 46. Transimpedance Amplifier

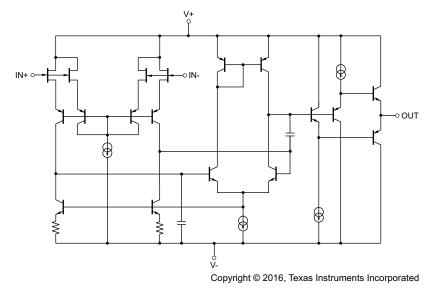


Figure 47. Equivalent Schematic (Single-Channel)

7.4 Device Functional Modes

The OPA827 has a single functional mode and is operational when the power-supply voltage is greater than 4 V (±2 V). The maximum power supply voltage for the OPA827 is 36 V (±18 V).



8 Application and Implementation

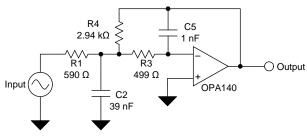
NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The OPA827 is a unity-gain stable, operational amplifier with very low noise, input bias current, and input offset voltage. Applications with noisy or high-impedance power supplies require decoupling capacitors placed close to the device pins. In most cases, 0.1-µF capacitors are adequate. Designers can easily take advantage of the low-noise characteristics of JFET amplifiers while also interfacing to modern, single-supply, precision data converters.

8.2 Typical Application



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Figure 48. 25-kHz Low-Pass Filter

8.2.1 Design Requirements

Low-pass filters are commonly employed in signal processing applications to reduce noise and prevent aliasing. The OPA827 is ideally suited to construct high-speed, high-precision active filters. Figure 48 shows a second-order, low-pass filter commonly encountered in signal processing applications.

Use the following parameters for this design example:

- Gain = 5 V/V (inverting gain)
- Low-pass cutoff frequency = 25 kHz
- · Second-order Chebyshev filter response with 3-dB gain peaking in the pass band

8.2.2 Detailed Design Procedure

The infinite-gain multiple-feedback circuit for a low-pass network function is shown in. Use Equation 3 to calculate the voltage transfer function.

$$\frac{\text{Output}}{\text{Input}}(s) = \frac{-1/R_1 R_3 C_2 C_5}{s^2 + (s/C_2)(1/R_1 + 1/R_3 + 1/R_4) + 1/R_3 R_4 C_2 C_5}$$
(3)

This circuit produces a signal inversion. For this circuit, the gain at DC and the low-pass cutoff frequency are calculated by Equation 4.

Gain =
$$\frac{R_4}{R_1}$$

 $f_C = \frac{1}{2\pi} \sqrt{(1/R_3 R_4 C_2 C_5)}$ (4)

Typical Application (continued)

Software tools are readily available to simplify filter design. WEBENCH® Filter Designer is a simple, powerful, and easy-to-use active filter design program. WEBENCH® Filter Designer lets you create optimized filter designs using a selection of TI operational amplifiers and passive components from TI's vendor partners.

Available as a web based tool from the WEBENCH Design Center, WEBENCH Filter Designer allows you to design, optimize, and simulate complete multistage active filter solutions within minutes.

8.2.3 Application Curve

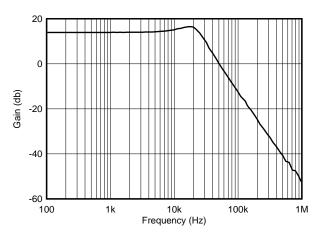


Figure 49. OPA827 Second-Order, 25-kHz, Chebyshev, Low-Pass Filter

8.3 System Examples

The OPA827 is well-suited for phase-lock loop (PLL) applications because of the low voltage offset, low noise, and wide gain bandwidth. Figure 50 illustrates an example of the OPA827 in this application. The first amplifier (OPA827) provides the loop low-pass, active filter function, while the second amplifier (OPA211) serves as a scaling amplifier. This second stage amplifies the DC error voltage to the appropriate level before it is applied to the voltage-controlled oscillator (VCO).

Operational amplifiers used in PLL applications are often required to have low voltage offset. As with other DC levels generated in the loop, a voltage offset applied to the VCO is interpreted as a phase error. An operational amplifier with inherently low voltage offset helps reduce this source of error. Also, any noise produced by the operational amplifiers modulates the voltage applied to the VCO and limits the spectral purity of the oscillator output. The VCO generates noise-related, random phase variations of its own, but this characteristic becomes worse when the input voltage source noise is included. This noise appears as random sideband energy that can limit system performance. The very low flicker noise (1/f) and current noise (In) of the OPA827 help to minimize the operational amplifier contribution to the phase noise.



System Examples (continued)

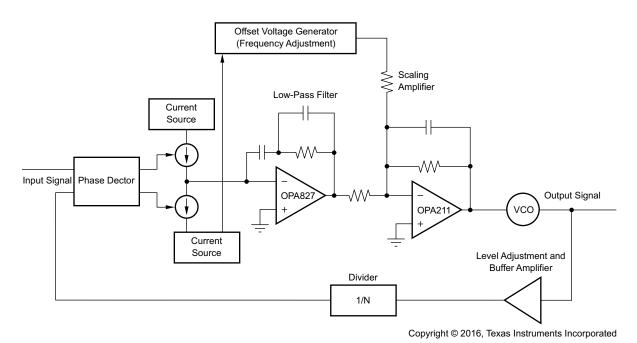


Figure 50. PLL Application

8.3.1 OPA827 Used as an I/V Converter

The OPA827 series of operation amplifiers have low current noise and offset voltage that make these devices a great choice for an I/V converter. DAC8811 is a single-channel, current output, 16-bit digital-to-analog converter (DAC). The I_{OUT} terminal of the DAC is held at a virtual GND potential by the use of the OPA827 as an external I/V converter op amp. The R-2R ladder is connected to an external reference input (V_{REF}) that determines the DAC full-scale current. The external reference voltage can vary in a range of –15 V to 15 V, thus providing bipolar I_{OUT} current operation. By using the OPA827 as an external I/V converter in conjunction with the internal DAC8811 R_{FB} resistor, output voltage ranges of $-V_{REF}$ to $+V_{REF}$ can be generated.

When using an external I/V converter and the DAC8811 R_{FB} resistor, the DAC output voltage is given by Equation 5.

$$V_{\text{OUT}} = \frac{-V_{\text{REF}} \times \text{CODE}}{65536}$$
NOTE
CODE is the digital input into the DAC.

The DAC output impedance as seen looking into the I_{OUT} terminal changes versus code. The low offset voltage of the OPA827 minimizes the error propagated from the DAC.

For a current-to-voltage design (see Figure 51), the DAC8811 I_{OUT} pin and the inverting node of the OPA827 must be as short as possible and adhere to good PCB layout design. For each code change on the output of the DAC, there is a step function. If the parasitic capacitance is excessive at the inverting node, then gain peaking is possible. For circuit stability, two compensation capacitors, C_1 and C_2 (4 pF to 20 pF typical) can be added to the design.

Some applications require full four-quadrant multiplying capabilities or a bipolar output swing. As shown in Figure 51, the OPA827 is added as a summing amp and has a gain of 2x that widens the output span to 20 V. A four-quadrant multiplying circuit is implemented by using a 10-V offset of the reference voltage to bias the OPA827.



System Examples (continued)

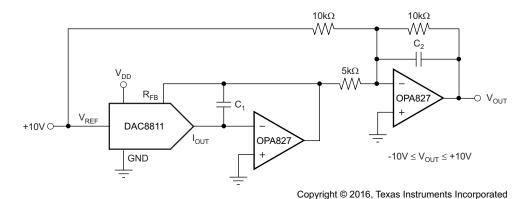


Figure 51. I/V Converter

9 Power Supply Recommendations

The OPA827 is specified for operation from 4 V to 36 V (±2 V to ±18 V); many specifications apply from –40°C to 125°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the *Absolute Maximum Ratings*.

CAUTION

Supply voltages larger than 40 V can permanently damage the device; see the *Absolute Maximum Ratings*.

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see *Layout*.



10 Layout

10.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and op amp itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for singlesupply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective
 methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground
 planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically
 separate digital and analog grounds paying attention to the flow of the ground current.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. As illustrated in Figure 52, keeping RF and RG close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.
- For best performance, TI recommends cleaning the PCB following board assembly.
- Any precision integrated circuit may experience performance shifts due to moisture ingress into the
 plastic package. Following any aqueous PCB cleaning process, TI recommends baking the PCB
 assembly to remove moisture introduced into the device packaging during the cleaning process. A low
 temperature, post cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.

10.2 Layout Example

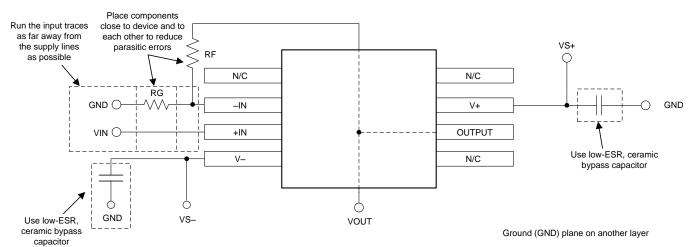


Figure 52. Operational Amplifier Board Layout for Noninverting Configuration



11 デバイスおよびドキュメントのサポート

11.1 デバイス・サポート

11.1.1 デベロッパー・ネットワークの製品に関する免責事項

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11.1.2 開発サポート

開発サポートについては、以下を参照してください。

- WEBENCH® Filter Designer
- OPA211
- DAC8811

11.2 ドキュメントのサポート

11.2.1 関連資料

関連資料については、以下を参照してください。

『トランスインピーダンス・アンプの直感的な補正』SBOA055

11.3 ドキュメントの更新通知を受け取る方法

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11.4 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

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11.7 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.



12 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。これらの情報は、指定のデバイスに対して提供されている最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
OPA827AID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 827 A	Samples
OPA827AIDG4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 827 A	Samples
OPA827AIDGKR	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	Call TI NIPDAUAG NIPDAU	Level-2-260C-1 YEAR	-40 to 125	NSP	Samples
OPA827AIDGKT	ACTIVE	VSSOP	DGK	8	250	RoHS & Green	Call TI NIPDAUAG NIPDAU	Level-2-260C-1 YEAR	-40 to 125	NSP	Samples
OPA827AIDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 827 A	Samples
OPA827AIDRG4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 827 A	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



PACKAGE OPTION ADDENDUM

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(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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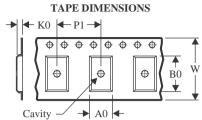
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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA827AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA827AIDR	SOIC	D	8	2500	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

www.ti.com 8-May-2024

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
OPA827AID	D	SOIC	8	75	506.6	8	3940	4.32
OPA827AIDG4	D	SOIC	8	75	506.6	8	3940	4.32



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



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